



Surface engineering of PDMS for improved triboelectrification†

Līva Ģērmane,^{id a} Linards Lapčinskis,^{id *ab} Mairis Iesalnieks^{id b} and
Andris Šutka^{id b}

Cite this: *Mater. Adv.*, 2023,
4, 875

Received 4th November 2022,
Accepted 11th January 2023

DOI: 10.1039/d2ma01015a

rsc.li/materials-advances

Here, we demonstrate an approach for improving the triboelectric charge in contact-separation of identical PDMS contact layers by three orders of magnitude. This is achieved by functionalization with self-assembled monolayers (SAMs) and combining rough and smooth surfaces. SAM-modified PDMS shows more stable surface charge in comparison to pristine PDMS.

Introduction

The rapid development of the Internet of Things (IoT) will increase the use of microelectronic devices. Therefore, the importance of sustainable and remote energy sources as alternatives to batteries is increasing. In the last decade, polymer-based triboelectric generator (TEG) devices have attracted attention for powering microdevices. TEG devices are capable of producing high output power density – up to 50 mW cm⁻² 1,2 and are attractive due to their low weight and large arsenal of available materials, as well as simple and low-cost fabrication process.^{3,4} Devices can be prepared in many designs that allow for flexible integration in wearables.^{5–7} TEGs harvest energy using the triboelectric effect: the charge formation happens when two distinct material surfaces are contact-separated against each other. Generally, the contact layers in TEGs are made from different polymer materials that are coated onto conductive electrodes. Upon contact-separation, the static surface charge is formed, which in turn induces an opposite charge on the underlying electrodes that are connected by the outer circuit. During the electrode movement the electric

potential of the TEG device changes and causes a displacement current between the electrodes.

Different approaches have been used to maximize the output power of the TEGs to fulfil the requirements set forward for self-powered electronics.⁸ Modification of the polymer surface morphology can increase the generated charge.^{9–14} An increase can also be achieved by optimising the architectures of the devices,^{15–19} doing chemical functionalization of the surfaces,²⁰ or adjusting the electronic and physicochemical properties of the contacting polymer materials.^{21–27}

Chemical surface functionalization by self-assembled monolayers (SAMs) has been previously reported as an effective strategy for increasing the magnitude of triboelectric surface charge.^{28,29} SAMs are ordered assemblies of organic molecules which can be covalently linked to various oxide, metal and polymer surfaces. Different polymers have been employed as substrates for SAM functionalization, such as polydimethylsiloxane (PDMS)^{30–32} and polyethylene terephthalate (PET).^{32–34} Most often TENGs are constructed using both PDMS and metallic electrodes modified by SAMs as contact layers. Chang *et al.* demonstrated that functionalization of PDMS with a fluorine-terminated SAM and an Al electrode with an amino-terminated SAM increased the generated current 4 times.³¹ Similarly, it has been shown that PDMS with fluorine-terminated SAMs reaches 60 times higher power density in comparison to pristine PDMS.³² Notably, fluorine-terminated SAMs on PDMS in combination with an ammonium bromide terminated SAM on a Ag electrode reached a power density of 39.4 W m⁻².³⁰ Regarding TENGs using polymers as both contact layers, Shin *et al.* demonstrated that a TENG reaching a power density of 55 W m⁻² can be constructed using two differently modified PET contact layers – one with an amine-based SAM and the other with a halogen-based SAM.³³

Here we show that the charge generated during contact separation of PDMS vs PDMS can be increased by three orders of magnitude by combining different SAMs on opposite PDMS. Furthermore, the generated charge density can be further enhanced or diminished if the contacted PDMS films have

^a Institute of Technical Physics, Faculty of Materials Science and Applied Chemistry, Riga Technical University, P. Valdena Street 3, LV1048, Riga, Latvia.
E-mail: linards.lapcinskis@rtu.lv

^b Institute of Materials and Surface Engineering, Faculty of Materials Science and Applied Chemistry, Riga Technical University, P. Valdena Street 3, LV1048, Riga, Latvia

† Electronic supplementary information (ESI) available. See DOI: <https://doi.org/10.1039/d2ma01015a>



different surface roughness, thus showing that the influence of surface morphology and SAM-type must be combined. The reason for the higher charge density when contacting SAM functionalized PDMS might be the formation of more stable charge species as confirmed by charge stability measurements.

Experimental and methods

Fabrication of PDMS samples

Flat PDMS samples were made by mixing PDMS precursor and curing agent (DOW, Sylgard™ 184) in ratio 10:1 and spin-coated on the ITO at 2500 rpm for 10 s. Then, the PDMS samples were cured at 80 °C for 3 h. The coating procedure was repeated two times to obtain the desired thickness. Samples with a rough surface were prepared in two steps. First, the primary PDMS layer was prepared as described above. Then caster sugar was added to PDMS before cross-linking for deposition of the secondary layer. The PDMS mixture containing sugar was spin-coated on top of a flat primary PDMS layer and cured under the same conditions at 80 °C for 12 h. After crosslinking, the sugar was dissolved by immersion in water. Finally, the obtained PDMS samples were dried in air at 60 °C for 24 hours. The size of the obtained sample films was 5 cm² while the thickness of the samples was 100 μm.

Chemical surface functionalization

Before surface functionalization, the PDMS samples were treated with O₂ plasma for 5 min to develop hydroxyl groups on the PDMS surface.³⁵ After plasma treatment, the samples were immediately immersed in ethanol-based solutions of (3-aminopropyl)triethoxysilane (APTES), 3-(trimethoxysilyl)propyl methacrylate (TMSPMA) and vinyltrimethoxysilane (VTMS) for an hour. The concentration of the solutions was 20 g L⁻¹. After treatment, the samples were left to dry in ambient air for 30 min.

Characterization

SEM images were obtained using a Hitachi TM3000 Table Top Scanning Electron Microscope. Attenuated total reflection Fourier-transform infrared spectra (ATR-FTIR) were obtained using a Vertex 70 (Bruker) spectrometer. Spectra were recorded at a resolution of 1 cm⁻¹ in the range from 600 to 4000 cm⁻¹. For each specimen, 25 consequential scans were performed to obtain the average spectrum. The X-ray Photoelectron Spectroscopy (XPS) spectra of these samples were collected with an ESCALAB Xi⁺ (Thermo Scientific). The transmittance of the TENG device was measured by a UV-vis spectroscopy method with a Genesys 10S spectrophotometer, Thermo Scientific.

Triboelectric measurements

Measurements were performed under controlled conditions – a separation distance of 5 mm, a pressing force of 10 N, and a contact–separation frequency of 1 Hz. To ensure repeatability, contact–separation was carried out using an Instron E1000 material testing machine. The generated current signals were

measured using a Keithley 6514 electrometer connected to a Picoscope 5444B PC oscilloscope system. The charge generated by individual PDMS films was determined after contact–separation with ITO, which was connected to an electrometer and the current was measured against the ground. This measurement setup was used as a Faraday cup mode to determine the magnitude and polarity of triboelectric charges formed on the PDMS samples (ESI† Fig. S1). The setup was verified by comparison of charge measurements using a custom-made Faraday cup. Measurements were done using the charge Q function of the Keithley 6514 electrometer (ESI† Fig. S2). The charge measured in Q mode was also compared to the charge calculated from current measurements of the PDMS sample to rule out the impact of Johnson noise on the charge values calculated from the current peaks (ESI† Fig. S3). The PDMS films were next used to prepare TENG devices (ESI† Fig. S4). In this case, both electrodes were connected to an electrometer. Surface charges, Q (nC), were calculated from the measured current peaks using the equation $Q = \int idt$, where i is the instantaneous current (nA) and dt is the differential of time (s). Integration was done for the high, narrow peaks which correspond to the separation stage. A detailed description of contact–separation test stages is given in the ESI† Fig. S5.

Instantaneous power was calculated using $P = V^2R^{-1}$ from the data obtained in voltage measurements at the corresponding load resistance R . Next, the instantaneous power was plotted as a function of time. Integration of the peak area allowed the calculation of the energy generated during separation. The peak duration was also determined from the plot and used to calculate the average power during the separation step using $P = E \times \Delta t^{-1}$. Energy density and power density were calculated by dividing the energy and power with the sample contact area.

Charge stability measurements

The stability of the charges generated after contact–separation was evaluated in contactless mode. Initially, PDMS and SAM-PDMS layers were contacted against ITO for 1000 contact–separation. Next, current was observed using contactless measurement by oscillating the PDMS or SAM-PDMS layer against an ITO connected to an electrometer and measuring current against ground. The oscillation frequency was 1 Hz and amplitude –5 mm.

Results and discussion

Four other electrodes (Al, Ni, Cu and Ti) besides the ITO were tested as substrates for the PDMS. It has been shown that the substrate can greatly influence the triboelectric performance.³⁶ The order of chosen additional electrodes and ITO in the triboelectric series is the following: ITO > Cu > Ni > Ti > Al.^{37–39} The results indicate that the highest charge density was observed when ITO was used as the substrate (0.7 nC cm⁻²) and charge density generally follows the order of material placement in the triboelectric series with Ni as an exception (Fig. S6,



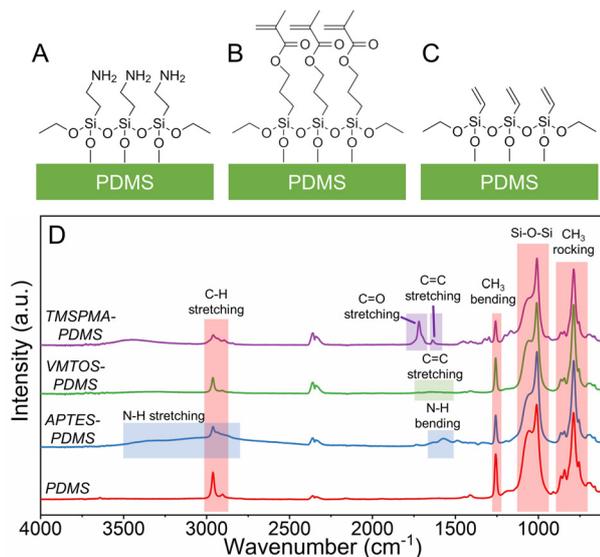


Fig. 1 Schematics of SAM-PDMS samples chemically functionalized by (A) APTES, (B) TMSPMA and (C) VTMS. (D) FTIR spectra of PDMS and SAM-PDMS.

ESI[†]). Placement of metals in the reported triboelectric series often varies, however, Cu and Ni in the triboelectric series often are placed close to each other; however, they show the highest disparity in the measured charge. The discrepancy from the expected tendency might be due to the presence of metal oxide passivation layers before the electrodes were coated with PDMS.

Fig. 1A–C demonstrates the schematics of SAM functionalized PDMS layers (SAM-PDMS), respectively, APTES-PDMS, TMSPMA-PDMS and VTMS-PDMS.

Successful chemical surface functionalization of PDMS samples was confirmed using ATR-FTIR spectroscopy. FTIR spectra of PDMS and SAM-PDMS layers were recorded in the wavenumber range of 600–4000 cm^{-1} , as shown in Fig. 1D. The main absorption bands of pristine PDMS are located at 789 cm^{-1} ($-\text{CH}_3$ rocking and Si–C stretching in Si– CH_3), 1050 cm^{-1} (Si–O–Si stretching), 1258 cm^{-1} (CH_3 bending in Si– CH_3), and 2962 cm^{-1} (asymmetric CH_3 stretching in Si– CH_3).⁴⁰ The addition of APTES was observed as the emergence of a strong peak at 1570 cm^{-1} (N–H bending) and a large broadband at 3350 cm^{-1} (N–H stretching).⁴¹ However, TMSPMA-treated PDMS showed additional peaks at 1720 cm^{-1} (C=O stretching) and 1638 cm^{-1} (C=C stretching).⁴² In the case of PDMS functionalized using VTMS, changes in the spectra were less apparent; this was evident by the emergence of a rather weak broadband at 1649 cm^{-1} (C=C stretching).⁴³

XPS was also used to confirm the formation of SAM-PDMS. The formation of SAM from APTES was verified by the appearance of the characteristic N 1s electron peak at 400 eV in comparison to other SAM-PDMS (ESI[†] Fig. S7). For TMSPMA-PDMS, smaller distinct peaks can be observed at 289.2 eV and 286.8 eV in the C 1s spectrum corresponding to C=O and C–O–C, respectively.

The influence of PDMS chemical functionalization on the generated triboelectric charge was tested by contacting pristine

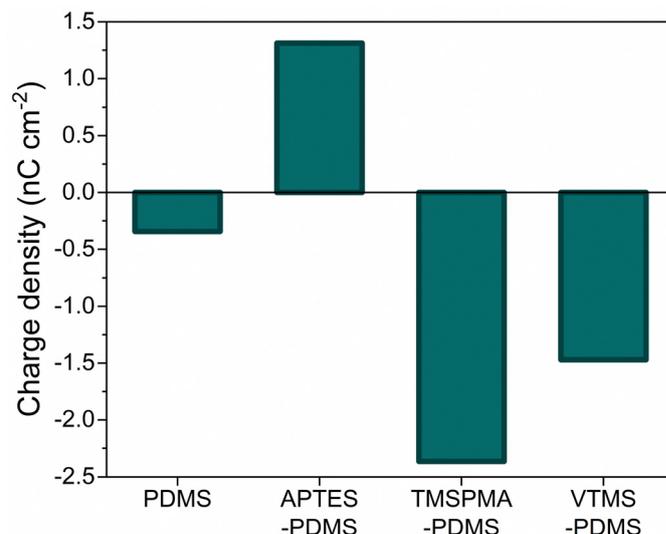


Fig. 2 Surface charge density of PDMS and SAM-PDMS samples in contact-separation against an ITO electrode connected to an electrometer to measure current against ground.

PDMS and SAM-PDMS films against the ITO electrode in Faraday cup mode, in which current is measured against ground. This makes it possible to determine the polarity of generated surface charge. For pristine PDMS, the calculated charge density was -0.34 nC cm^{-2} (Fig. 2). In the case of APTES-PDMS the observed charge was positive, accordingly 1.31 nC cm^{-2} , while for TMSPMA-PDMS and VTMS-PDMS it was negative: -2.36 nC cm^{-2} and -1.47 nC cm^{-2} , respectively. Notably, for all SAM-PDMS the charge density was higher than for the pristine PDMS when contacting the ITO electrode. This could arise due to inductive effects in the SAM molecules. It is a local change in the electron density due to electron-withdrawing or electron-donating groups in the molecule, resulting in a permanent dipole in a bond. As previously shown, dipoles (ferroelectric and instantaneous surface dipoles upon separation) can be matched in TENG devices to obtain higher performance.⁴⁴ Here, end groups found in SAM molecules, such as NH_2 in APTES, and vinyl groups in TMSPMA and VTMS, create a polarized bond. While the impact of a single dipole on the electrostatic properties might be negligible, SAM molecules cover the whole surface resulting in a significant influence.

Contact-separation between two pristine PDMS with identical crosslinking degree results in a negligible charge density ($0.001\text{--}0.002 \text{ nC cm}^{-2}$).^{23,25} Since APTES-PDMS film shows a positive charge density but the highest negative charge was obtained for TMSPMA-PDMS film, this combination was chosen to assemble a TENG using SAM-PDMS as both contact layers. The assembled TENG demonstrated charge density of 1.16 nC cm^{-2} (Fig. 3A), V_{OC} of 70 V and I_{SC} of 700 nA (ESI[†] Fig. S8 and S9). The observed charge density is three orders of magnitude higher than that observed in contact-separation of two identical pristine PDMS layers. For comparison, TENGs were also assembled using different SAM-PDMS combinations. TENG using APTES-PDMS and VTMS-PDMS, which are also



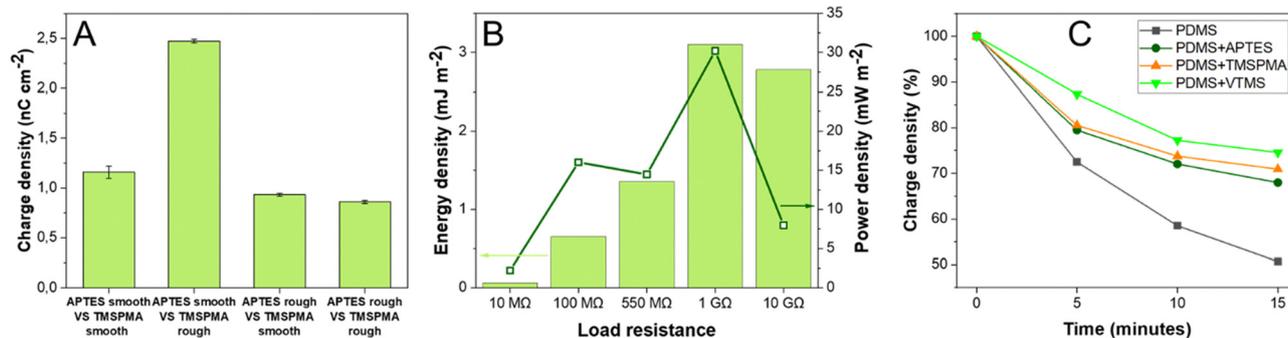


Fig. 3 (A) Charge densities of TENGs based on APTES-PDMS and TMSPMA-PDMS films with various surface roughness. (B) Energy and power density of the TENG device based on smooth APTES-PDMS and rough TMSPMA-PDMS. (C) Current observed in contactless mode between pristine ITO and PDMS layers after 1000 contact-separation cycles.

charged negatively, showed the charge density of only 0.49 nC cm^{-2} . When a TENG was built using both samples that are charged negatively – VTMS-PDMS and TMSPMA-PDMS, the charge density was merely 0.29 nC cm^{-2} .

Charge density can be further increased by using rough and smooth surfaces as contact layers. SEM images of smooth and rough PDMS are shown in ESI† Fig. S10A and B, respectively. As shown in Fig. 2 the charge density after smooth PDMS was contact separated against ITO was 0.34 nC cm^{-2} . Accordingly, the surface charge of rough PDMS was also determined in Faraday cup mode after contact-separation against ITO. The charge density reached -0.6 nC cm^{-2} , which was more negative than in the case of smooth PDMS.

Next, both the smooth and rough films were functionalized by SAM. Since rough PDMS had shown relatively more negative charge, TMSPMA was introduced on the rough PDMS layer and accordingly for the smooth PDMS, with the less negative charge, the APTES SAM was used. Notably, a charge density of 2.50 nC cm^{-2} was obtained when smooth APTES-PDMS was contacted against rough TMSPMA-PDMS, as shown in Fig. 3A (corresponding current peaks are shown in ESI† Fig. S11–S13). Accordingly, when rough APTES-PDMS was contact-separated against smooth TMSPMA-PDMS almost 3 times lower charge density was registered (0.93 nC cm^{-2}). This observation is in line with our previous results that contact-separation can be boosted by increasing the difference in surface roughness of both layers.⁴⁵ Evidently, the direction of triboelectric dipole that forms between contact-separated layers is influenced both by the surface roughness and the type of SAM used for functionalization. These effects can be combined to obtain higher surface charge. In future studies this effect could be combined with other factors that influence the charge formation⁴⁴ in contact-separation to achieve even greater triboelectric performance.

For the TENG assembled using smooth APTES-PDMS and rough TMSPMA-PDMS as contacting layers, the highest generated energy density of 3 mJ m^{-2} was observed at $1 \text{ G}\Omega$ load resistance (Fig. 3B green bars). $1 \text{ G}\Omega$ resistance was also the optimal load resistance for this TENG device since the highest power density of 31 mW m^{-2} was obtained from voltage

measurements at this value (Fig. 3B dark green squares). For comparison, the TENG which was assembled using smooth APTES-PDMS and smooth TMSPMA-PDMS layers demonstrated the energy density of only 0.18 mJ m^{-2} at $1 \text{ G}\Omega$ and power density of 2.5 mW m^{-2} (ESI† Fig. S14). The observed energy and power densities suggest that the TENG device based on rough APTES-PDMS and smooth TMSPMA-PDMS layers with coordinated surface roughness values might be sufficient to power portable electronic devices. Since the TENG is assembled using PDMS/ITO as an electrode, the whole device is transparent, and for the TENG based on smooth APTES-PDMS and smooth TMSPMA-PDMS the visible light transmittance reaches 70% (ESI† Fig. S15). However, for the TENG based on smooth APTES-PDMS and rough TMSPMA-PDMS, the transmittance reaches only 25%. Nevertheless, transparency enables future application in optoelectronics or self-powered electronic displays and touchscreens.

Surface charge density is linked with the presence of mechanoradicals on the polymer surface and the formation of stable ion-radical pairs.⁴⁶ Accordingly, an increase in the charge density generated during contact-separation for functionalized PDMS can be explained by the formation of relatively more stable ion-radical pairs. To test whether SAM-PDMS indeed possesses better charge stability, we performed non-contact oscillation of the charged films. Charge stability tests showed that for SAM-PDMS the decrease in charge density was lower than for non-functionalized PDMS. For non-functionalized PDMS after 15 min of oscillation the charge density decreased by 50% of the initial value (Fig. 3C). For SAM-PDMS layers the charge decrease in the same time period was much lower – APTES-PDMS decreased by 32%, TMSPMA-PDMS by 29% and VTMS-PDMS only by 25%.

Conclusions

In summary, the charge density generated in contact-separation of PDMS contact layers with identical crosslink degrees is increased by three orders of magnitude when one PDMS is functionalized by APTES and the other by TMSPMA.



Charge density is further increased when contact-separating smooth and rough surfaces – the greatest charge density is seen for the combination of smooth APTES-PDMS and rough TMSPMA-PDMS. The obtained TENGs are transparent, thus opening pathways to incorporation in optoelectronic systems. Measurements in non-contact oscillation mode reveal that SAM-modified PDMS layers show higher charge density stability than pristine PDMS.

Author contributions

L. Ğ. performed sample fabrication, surface functionalization and triboelectric measurements. L. L. performed ATR-FTIR measurements and charge stability tests. M. I. performed the XPS measurements. L. L. and A. Š conceived the idea. The manuscript was written through the contributions of all authors. All authors have given approval to the final version of the manuscript.

Conflicts of interest

There are no conflicts of interest to declare.

Acknowledgements

L. Ğ. acknowledges the financial support from the grant: “Strengthening the capacity of RTU scientific staff”, project No. ZM-2021/14.

Notes and references

- L. Lapčinskis, K. Mālnieks, A. Linarts, J. Blūms, K. Šmits, M. Järvekūlg, M. Knite and A. Šutka, *ACS Appl. Energy Mater.*, 2019, **2**, 4027.
- M. Kim, D. Park, M. M. Alam, P. Park and J. Nah, *ACS Nano*, 2019, **13**, 4640.
- J. Li, N. A. Shepelin, P. C. Sherrell and A. V. Ellis, *Chem. Mater.*, 2021, **33**, 4304.
- B.-Y. Lee, D. H. Kim, J. Park, K.-I. Park, K. J. Lee and C. K. Jeong, *Sci. Technol. Adv. Mater.*, 2019, **20**, 758.
- G. Zhu, P. Bai, J. Chen and Z. L. Wang, *Nano Energy*, 2013, **2**, 688.
- I. Aazem, D. T. Mathew, S. Radhakrishnan, K. V. Vijoy, H. John, D. M. Mulvihill and S. C. Pillai, *RSC Adv.*, 2022, **12**, 10545.
- J. Zhong, Y. Zhang, Q. Zhong, Q. Hu, B. Hu, Z. L. Wang and J. Zhou, *ACS Nano*, 2014, **8**, 6273.
- Y. Wu, Y. Luo, T. J. Cuthbert, A. V. Shokurov, P. K. Chu, S.-P. Feng and C. Menon, *Adv. Sci.*, 2022, **9**, 2106008.
- S. A. Lone, K. C. Lim, K. Kaswan, S. Chatterjee, K.-P. Fan, D. Choi, S. Lee, H. Zhang, J. Cheng and Z.-H. Lin, *Nano Energy*, 2022, **7**, 107318.
- S. Zhang, C. Qu, Y. Xiao, H. Liu, G. Song and Y. Xu, *Nanoscale*, 2022, **14**, 4244.
- Y. Song, W. Gao and H. Zhang, in *Integrated Smart Micro-Systems Towards Personalized Healthcare*, Wiley-VCH Verlag GmbH, Weinheim, 2022, Chapter 3, 77–99.
- S. Wu, G. Li, W. Liu, D. Yu, G. Li, X. Liu, Z. Song, H. Wang and H. Liu, *Nano Energy*, 2022, **93**, 106859.
- B. Dudem, Y. H. Ko, J. W. Leem, S. H. Lee and J. S. Yu, *ACS Appl. Mater. Interfaces*, 2015, **7**, 20520.
- L. Zhang, B. Zhang, J. Chen, L. Jin, W. Deng, J. Tang, H. Zhang, H. Pan, M. Zhu, W. Yang and Z. L. Wang, *Adv. Mater.*, 2016, **28**, 1650.
- Q. Sun, L. Wang, G. Ren, L. Zhang, H. Sheng, Y. Zhu, H. Wang, G. Lu, H.-D. Yu and W. Huang, *Nano Energy*, 2022, **92**, 106840.
- C.-R. Yang, C.-T. Ko, S.-F. Chang and M.-J. Huang, *Nano Energy*, 2022, **92**, 106791.
- Z. Chen, Y. Cao, W. Yang, L. An, H. Fan and Y. Guo, *J. Mater. Chem. A*, 2022, **10**, 799.
- B. Chai, K. Shi, H. Zou, P. Jiang, Z. Wu and X. Huang, *Nano Energy*, 2022, **91**, 106668.
- G. Zu, Y. Wei, C. Sun and X. Yang, *J. Mater. Chem.*, 2022, **57**, 2813.
- S. Wang, Y. Zi, Y. S. Zhou, S. Li, F. Fan, L. Lin and Z. L. Wang, *J. Mater. Chem. A*, 2016, **4**, 3728.
- J. Chen and Z. L. Wang, *Joule*, 2017, **1**, 480.
- A. Šutka, A. Linarts, K. Mālnieks, K. Stiprais and L. Lapčinskis, *Mater. Horiz.*, 2020, **7**, 520.
- A. Šutka, K. Mālnieks, L. Lapčinskis, P. Kaufelde, A. Linarts, A. Bērziņa, R. Zābels, V. Jurkāns, I. Gorņevs, J. Blūms and M. Knite, *Energy Environ. Sci.*, 2019, **12**, 2417.
- L. Lapčinskis, K. Mālnieks, J. Blūms, M. Knite, S. Oras, T. Kāāmbre, S. Vlassov, M. Antsov, M. Timusk and A. Šutka, *Macromol. Mater. Eng.*, 2020, **305**, 1900638.
- P. C. Sherrell, A. Šutka, N. A. Shepelin, L. Lapčinskis, O. Verners, L. Germane, M. Timusk, R. A. Fenati, K. Mālnieks and A. V. Ellis, *ACS Appl. Mater. Interfaces*, 2021, **13**, 44935.
- H. Zou, Y. Zhang, L. Guo, P. Wang, X. He, G. Dai, H. Zheng, C. Chen, A. C. Wang, C. Xu and Z. L. Wang, *Nat. Commun.*, 2019, **10**, 1427.
- S. Li, Y. Fan, H. Chen, J. Nie, Y. Liang, X. Tao, J. Zhang, X. Chen, E. Fu and Z. L. Wang, *Energy Environ. Sci.*, 2020, **13**, 896.
- Y. Yang, H. Zhang, J. Chen, S. Lee, T.-C. Hou and Z.-L. Wang, *Energy Environ. Sci.*, 2013, **6**, 1744–1749.
- A. Ulman, *Chem. Rev.*, 1996, **96**, 1533.
- Y.-H. Cheng, C.-J. Lee and C.-Y. Chang, *Adv. Mater. Technol.*, 2021, **6**, 2000985.
- C. Chang and C. Wang, *J. Mater. Chem. C*, 2020, **8**, 4542.
- G. Song, Y. Kim, S. Yu, M.-O. Kim, S.-H. Park, S. M. Cho, D. B. Velusamy, S. H. Cho, K. L. Kim, J. Kim, E. Kim and C. Park, *Chem. Mater.*, 2015, **27**, 4749.
- S.-H. Shin, Y. E. Bae, H. K. Moon, J. Kim, S.-H. Choi, Y. Kim, H. J. Yoon, M. H. Lee and J. Nah, *ACS Nano*, 2017, **11**, 6131.
- S.-H. Shin, Y. H. Kwon, Y.-H. Kim, J.-Y. Jung, M. H. Lee and J. Nah, *ACS Nano*, 2015, **9**, 4621.
- R. Wolf and A. Sparavigna, *Engineering*, 2010, **2**, 397.
- M. Siek, W. Adamkiewicz, Y. I. Sobolev and B. A. Grzybowski, *Angew. Chem., Int. Ed.*, 2018, **57**, 15379.
- S. Pan and Z. Zhang, *Friction*, 2019, **7**, 2.
- A. Okbaz, A. Karabiber, A. Yar, Z. Kinas, A. Sarilmaz and F. Ozel, *Energy Convers. Manage.*, 2022, **252**, 115053.
- R. Zhang, M. Hummelgård, J. Örtengren, M. Olsen, H. Andersson, Y. Yang, Z.-L. Wang, H. Olin, P. Sutar and D. Mihailovic, *Nano Energy*, 2021, **89**, 106363.



- 40 L. Johnson, L. Gao, C. W. Shields IV, M. Smith, K. Efimenko, K. Cushing, J. Genzer and G. P. López, *J. Nanobiotechnol.*, 2013, **11**, 22.
- 41 T.-N. Le and C.-K. Lee, *Appl. Biochem. Biotechnol.*, 2020, **191**, 29.
- 42 V. Kumar, U. H. Ko, Y. Zhou, J. Hoque, G. Arya and S. Varghese, *Adv. Intell. Syst.*, 2021, **3**, 2100005.
- 43 M. A. Sibeko and A. S. Luyt, *Polym. Bull.*, 2014, **71**, 637.
- 44 A. Šutka, K. Mālnieks, L. Lapčinskis, M. Timusk, K. Pudzs and M. Rutkis, *iScience*, 2020, **23**, 101011.
- 45 A. Šutka, K. Mālnieks, L. Lapčinskis, M. Timusk, K. Kalniņš, A. Kovaļovs, J. Bītenieks, M. Knite, D. Stevens and J. Grunlan, *Phys. Chem. Chem. Phys.*, 2020, **22**, 13299.
- 46 T. Mazur and B. A. Gryzbowski, *Chem. Sci.*, 2017, **8**, 2025.

